



High-end Power Semiconductor Manufacturer

ZK400A 1100-2000V

Fast Recovery Diode

- Low switching losses
- Low reverse recovery charge High
- power cycling capability



Average forward current			I _{FAV}	390 A			
Repetitive peak reverse voltage			V _{RRM}	1100 – 2000 V			
Reverse recovery time			t _{rr}	2.00 µs			
V _{RRM} , V	1100	1200	1400	1600	1800	2000	
Voltage code	11	12	14	16	18	20	
T _j , °C	– 60 – 150						

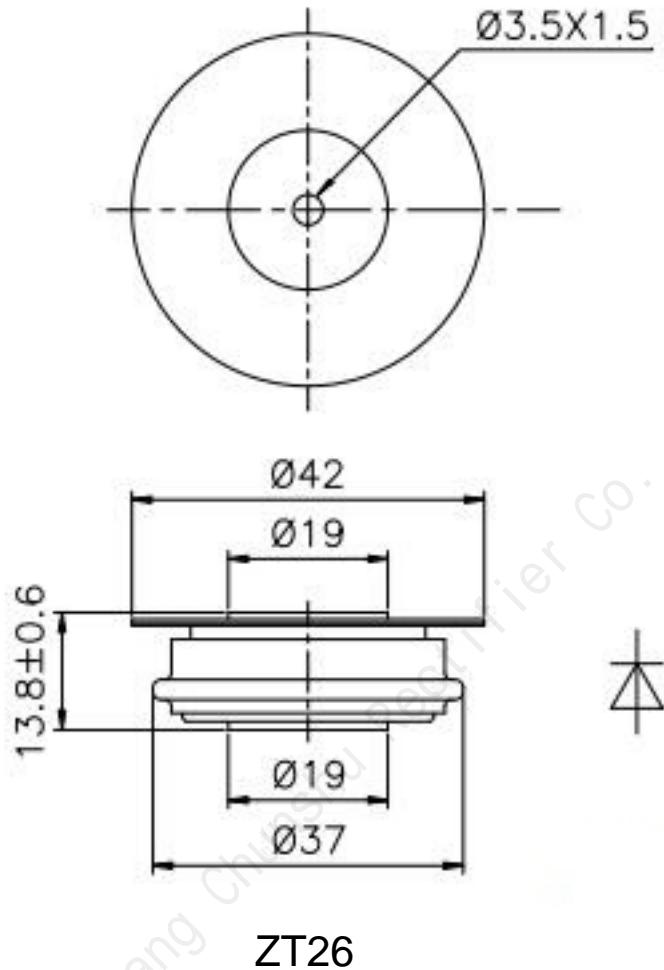
MAXIMUM ALLOWABLE RATINGS

Symbols and parameters		Units	Values	Test conditions	
ON-STATE					
I _{FAV}	Average forward current	A	390	T _c =85 °C; Double side cooled; 180° half-sine wave; 50 Hz	
I _{FSM}	Surge forward current	kA	5.4	T _j =T _{j max}	180° half-sine wave; t _p =10 ms; V _R =0.6V _{RRM}
I ² t	Safety factor	A ² ·10 ³	146	T _j =T _{j max}	180° half-sine wave; t _p =10 ms; V _R =0.6V _{RRM}
BLOCKING					
V _{RRM}	Repetitive peak reverse voltages	V	1100–2000	t _p =10 ms	
V _R	Reverse continuous voltages	V	0.6V _{RRM}	T _j =T _{j max} ;	
THERMAL					
T _{stg}	Storage temperature	°C	–40–160		
T _j	Operating junction temperature	°C	–60 –150		
MECHANICAL					
F	Mounting force	kN	3.3 – 5.5		

CHARACTERISTICS

Symbols and parameters		Units	Values	Conditions
ON-STATE				
V_{Fm}	Peak forward voltage, max	V	2.40	$T_j=25\text{ }^{\circ}\text{C}$; $I_{TM}=600\text{A}$, $F=5.0\text{kN}$
$V_{F(TO)}$	Forward threshold voltage, max	V	1.48	
r_T	Forward slope resistance, max	$\text{m}\Omega$	0.65	$T_j=T_{j\max}$;
BLOCKING				
I_{RRM}	Repetitive peak reverse current, max	mA	20	$T_j=T_{j\max}$; $V_R=V_{RRM}$
SWITCHING				
Q_{rr}	Total recovered charge, max	μC	70	$I_{TM}=1000\text{A}$, $t_p=2000\mu\text{s}$, $-di/dt=60\text{A}/\mu\text{s}$,
t_{rr}	Reverse recovery time ¹⁾ , max	μs	2.00	$V_R=50\text{V}$
THERMAL				
R_{thjc}	Thermal resistance, junction to case, max	$^{\circ}\text{C}/\text{W}$	0.0800	Clamping force 5.0kN
R_{thck}	Thermal resistance, case to heatsink, max	$^{\circ}\text{C}/\text{W}$	0.0200	Clamping force 5.0kN
MECHANICAL				
W	Weight, max	g	60	

OVERALL DIMENSIONS



All dimensions in millimeters